PATENT COOPERATION TREATY

From the INTERNATIONAL SEARCHING AUTHORITY

REC'D	1	6	MAR	2006
WIPO	_			PCT

To: SEMICONDUCTOR ENERGY	LABORATORY
CO.,LTD.	-

398, Hase, Atsugi -shi, Kanagawa 2430036 Japan

PCI

WRITTEN OPINION OF THE INTERNATIONAL SEARCHING AUTHORITY (PCT Rule 43 bis. 1)

Date of mailing (day/month/year)

14.03.2006

Applicant's or agent's file reference 00000PCT8407

FOR FURTHER ACTION

See paragraph 2 below

International application No. PCT/JP2005/022608

International filing date (day/month/year)
02.12.2005

Priority date (day/month/year)
06.12.2004

International Patent Classification (IPC) or both national classification and IPC

Int.Cl. G09F9/30(2006.01), H01L21/3205(2006.01), H01L29/786(2006.01), H01L51/50(2006.01)

Applicant

SEMICONDUCTOR ENERGY LABORATORY CO., LTD.

1.	This opinion contains indications relating to the following items:					
	V	Box No. I	Basis of the opinion			
		Box No. II	Priority			
	T.	Box No. III	Non-establishment of opinion with regard to novelty, inventive step and industrial applicability			
	V	Box No. IV	Lack of unity of invention			
	Ø	Box No. V	Reasoned statement under Rule 43 bis.1(a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement			
	D	Box No. VI	Certain documents cited			
٠		Box No. VII	Certain defects in the international application			
		Вох №. VШ	Certain observations on the international application			

2. FURTHER ACTION

If a demand for international preliminary examination is made, this opinion will be considered to be a written opinion of the International Preliminary Examining Authority ("IPEA") except that this does not apply where the applicant chooses an Authority other than this one to be the IPEA and the chosen IPEA has notified the International Bureau under Rule 66.1bis(b) that written opinious of this International Searching Authority will not be so considered.

If this opinion is, as provided above, considered to be a written opinion of the IPEA, the applicant is invited to submit to the IPEA a written reply together, where appropriate, with amendments, before the expiration of 3 months from the date of mailing of Form PCT/ISA/220 or before the expiration of 22 months from the priority date, whichever expires later.

For further options, see Form PCT/ISA/220.

3. For further details, see notes to Form PCT/ISA/220.

Date of completion of this opinion 06.03.200	·			
Name and mailing address of the ISA/JP	Authorized officer		2G	9508
· · · · · · · · · · · · · · · · · · ·	HATAE Susumu	17act	3226	
3-4-3, Kasumigaseki, Chiyoda-ku, Tokyo 100-8915, Japan	Telephone No. +81-3-3581-1101	EXI.	3220	

Form PCT/ISA/237 (cover sheet) (April 2005)

International application No.

PCT/JP2005/022608

Bax No. I	Basis of the opinion	
1. With	regard to the language, this opinion has been established on the basis of: the international application in the language in which it was filed a translation of the international application into translation furnished for the purposes of international search (Rules 12.3(a) and 23.1(b)).	, which is the language of a
2. With claim	regard to any nucleotide and/or amino acid sequence disclosed in the international a ned invention, this opinion has been established on the basis of:	pplication and necessary to the
a. tyr	pe of material	
Г	•	
[table(s) related to the sequence listing	
ь. fo С Г	•	٠
į. Į	me of filing/furnishing contained in the international application as filed filed together with the international application in electronic form furnished subsequently to this Authority for the purposes of search In addition, in the case that more than one version or copy of a sequence listing and/or filed or furnished, the required statements that the information in the subsequent or ad the conficution as filed as appropri	
4. Add	filed or furnished, the required statements that the information in the successful in the application as filed or does not go beyond the application as filed, as appropri ditional comments:	ate, were furnished.
		÷ .

International application No.
PCT/JP2005/022608

Box No.	IV	Lack of unity of invention
1. 区	ln resp	conse to the invitation (Form PCT/ISA/206) to pay additional fees the applicant has, within the applicable time limit:
	Γ.	paid additional fees
		paid additional fees under protest and, where applicable, the protest fee
		paid additional fees under protest but the applicable protest fee was not paid
	V	not paid additional fees
2. [Authority found that the requirement of unity of invention is not complied with and chose not to invite the applicant to idditional fees.
3. Thi	s Autho	ority considers that the requirement of unity of invention in accordance with Rule 13.1, 13.2 and 13.3 is
Г.	con	nplied with
V	not	complied with for the following reasons:
sig sup ser Thu	n final pply ies, on the man	aim 2 does not include a process for manufacture of insulating alm in a portion under at least one of the plurality of source lines, the plurality of gate signal lines, the plurality of power lines in column, and the plurality of power supply lines in which is a special technical feature in claim 1. Claim 2 is not considered to be a process specially adopted for mufacture of the display device of claim 1. There is no unity in claims 1 and 2.
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İ		
1		
4. (Conseq	uently, this opinion has been established in respect of the following parts of the international application:
		all parts
	Z i	he parts relating to claims Nos. 1, 3-5

International application No.

PCT/JP2005/022608

Box No. V	Reasoned statement un citations and explanat		bis.1(a)(i) with regard to novelty, inventive step or industrial applicing such statement	cability;
1. Staten	nent			
No	ovelty (N)	Claims	1, 3-5	YES
		Claims		. NO
In	ventive step (IS)	Claims		YES
		Claims	1, 3-5	NO
. In	dustrial applicability (IA)	Claims	1, 3-5	YES
		Claims		NO
	•			
D2: W	O 98/36407 A1 P 2001-53287 A	(SEIKO (Semico	cox CO., Ltd.) 1993.02.12 EPSON CO.) 1998.08.20 Enductor Energy Laboratory CO.) 2001.0)2.23,
inven	tive step in vi	ew of t	laims 1, 4 and 5 do not appear to involute D1, D2 and D3.	
D	1 discloses matr	ix EL d	isplay device including switching signal	. lines
Y, in:	formation signa	l lines	X, power drive lines Z in column and refirst switching elements Qw and second switching	tching
eleme	$nts O_d$ (see [00	181, [0	023] and figs 1, 3).	
l D	2 discloses disp	lav dev	ice including data lines "sig", scanning :	signal
lines	"gate", capacit	or line	s "cline" (corresponding to power supply	lines
inse	ries), common po	wer sup	ply lines "com" (corresponding to power:	q alla
lines	in column), lum	inescer d fig 2)	at elements 40, first TFTs 20 and secon . D2 also discloses a method of forming sc	anning
signa	l lines by sout	terina	method (see page 23).	

D3 discloses second interlayer insulating films which are selectively disposed only at the region where the gate electrode and the second wirings overlap with each other (see [0034] -[0036], Figures 5, 7, 8).

It would be obvious for the person skilled in the art to apply second interlayer insulating films in D3 to display device in D1 or D2.

Claim 3

The subject matter of claim 3 does not appear to involve an inventive step in view of the D1, D2, D3 and D4.

D4 discloses a method of forming insulating layers by ink jet method (see [0022]). It would be obvious for the person skilled in the art to form second interlayer insulating films in D3 by ink jet method according to D4.

PATENT COOPERATION TREATY

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FOR FURTHER ACTION

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	F.	Box No. IV	Lack of unity of invention			
	M	Box No. V	Reasoned statement under Rule 43bis.1(a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement			
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2. FURTHER ACTION

If a demand for international preliminary examination is made, this opinion will be considered to be a written opinion of the International Preliminary Examining Authority ("IPEA") except that this does not apply where the applicant chooses an Authority other than this one to be the IPEA and the chosen IPEA has notified the International Bureau under Rule 66.1bis(b) that written opinions of this International Searching Authority will not be so considered.

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For further options, see Form PCT/ISA/220.

For further details, see notes to Form PCT/ISA/220.

Date of completion of this opinion 06.03.200	6			
Name and mailing address of the ISA/JP	Authorized officer		2G	9508
Japan Patent Office 3-4-3, Kasumigaseki, Chiyoda-ku, Tokyo 100-8915, Japan	HATAE Susumu Telephone No. +81-3-3581-1101	Ext.	3226	

Form PCT/ISA/237 (cover sheet) (April 2005)

International application No.

PCT/JP2005/022608

Bax	No. I	Basis of the opinion						
	With	regard to the language, this opinion has been established on the basis of: the international application in the language in which it was filed a translation of the international application into translation furnished for the purposes of international search (Rules 12.3(a) and 23.1(b)).						
2.	With regard to any nucleotide and/or amino acid sequence disclosed in the international application and necessary to the claimed invention, this opinion has been established on the basis of:							
	a. typ	e of material						
	Г	·						
		table(s) related to the sequence listing						
	b. fo	mat of material						
	E	on paper						
	Γ	in electronic form						
	c. ti	ne of filing/furnishing						
		contained in the international application as filed						
	Г							
	Ī.	furnished subsequently to this Authority for the purposes of search						
3.	In addition, in the case that more than one version or copy of a sequence listing and/or table(s) relating thereto has been filed or furnished, the required statements that the information in the subsequent or additional copies is identical to that in the application as filed or does not go beyond the application as filed, as appropriate, were furnished.							
4.	Ado	itional comments:						
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International application No.
PCT/JP2005/022608

Box No. IV	Lack of unity of invention							
1. 🔽 ln resp	ponse to the invitation (Form PCT/ISA/206) to pay additional fees the applicant has, within the applicable time limit:							
Γ.	paid additional fees							
	paid additional fees under protest and, where applicable, the protest fee							
I.	paid additional fees under protest but the applicable protest fee was not paid							
⊠	not paid additional fees							
	Authority found that the requirement of unity of invention is not complied with and chose not to invite the applicant to additional fees.							
3. This Author	ority considers that the requirement of unity of invention in accordance with Rule 13.1, 13.2 and 13.3 is							
con	pplied with							
. Iv not	complied with for the following reasons:							
thin film in a portion under at least one of the plurality of sour signal lines, the plurality of gate signal lines, the plurality of pow supply lines in column, and the plurality of power supply lines series, which is a special technical feature in claim 1. Thus, claim 2 is not considered to be a process specially adopted for the manufacture of the display device of claim 1. There is no unipoetween claims 1 and 2.								
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	•							
	·							
4. Consequently, this opinion has been established in respect of the following parts of the international application:								
	all parts							
	he parts relating to claims Nos. 1, 3-5							

International application No.

PCT/JP2005/022608

Box No. V	Reasoned statement under Rule 43bis. 1(a)(i) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement				
1. Stateme	ent				
No	velty (N)	Claims Claims	1, 3-5	YES NO	
Inv	entive step (IS)	Claims	1. 3-5	YES NO	

YES 1, 3-5 Industrial applicability (IA) Claims Claims

Citations and explanations:

D1: JP 5-35207 A (Fuji Xerox CO., Ltd.) 1993.02.12

D2: WO 98/36407 A1 (SEIKO EPSON CO.) 1998.08.20

D3: JP 2001-53287 A (Semiconductor Energy Laboratory CO.) 2001.02.23,

D4: JP 2003-177682 A (KONICA CO.) 2003.06.27

Claims 1, 4, 5

The subject matter of claims 1, 4 and 5 do not appear to involve an inventive step in view of the D1, D2 and D3.

D1 discloses matrix EL display device including switching signal lines Y, information signal lines X, power drive lines Z in column and row, EL light emitting elements C_{EL} , first switching elements Q_{W} and second switching elements Q_d (see [0018], [0023] and figs 1, 3).

D2 discloses display device including data lines "sig", scanning signal lines "gate", capacitor lines "cline" (corresponding to power supply lines in series), common power supply lines "com" (corresponding to power supply lines in column), luminescent elements 40, first TFTs 20 and second TFTs 30 (see pages 15-16 and fig 2). D2 also discloses a method of forming scanning signal lines by sputtering method (see page 23).

D3 discloses second interlayer insulating films which are selectively disposed only at the region where the gate electrode and the second wirings overlap with each other (see [0034] -[0036], Figures 5, 7, 8).

It would be obvious for the person skilled in the art to apply second interlayer insulating films in D3 to display device in D1 or D2.

Claim 3

The subject matter of claim 3 does not appear to involve an inventive step in view of the D1, D2, D3 and D4.

D4 discloses a method of forming insulating layers by ink jet method (see [0022]). It would be obvious for the person skilled in the art to form second interlayer insulating films in D3 by ink jet method according to D4.